

Surface Mount Attenuator
2 Watts, 4 dB



Features:

- RoHS Compliant
- 2 Watts
- Low Cost
- DC – 6.0GHz
- Al₂O₃ Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

Description:

The XRA2GG4SES is a high performance Alumina (Al₂O₃) chip attenuator intended as a cost competitive alternative to Beryllium Oxide (BeO). It is designed particularly for LTE and 5G wireless communication frequency bands. The high power handling makes the part ideal for inter-stage matching, directional couplers, and for use in isolators. The attenuator is also RoHS compliant!

General Specifications:

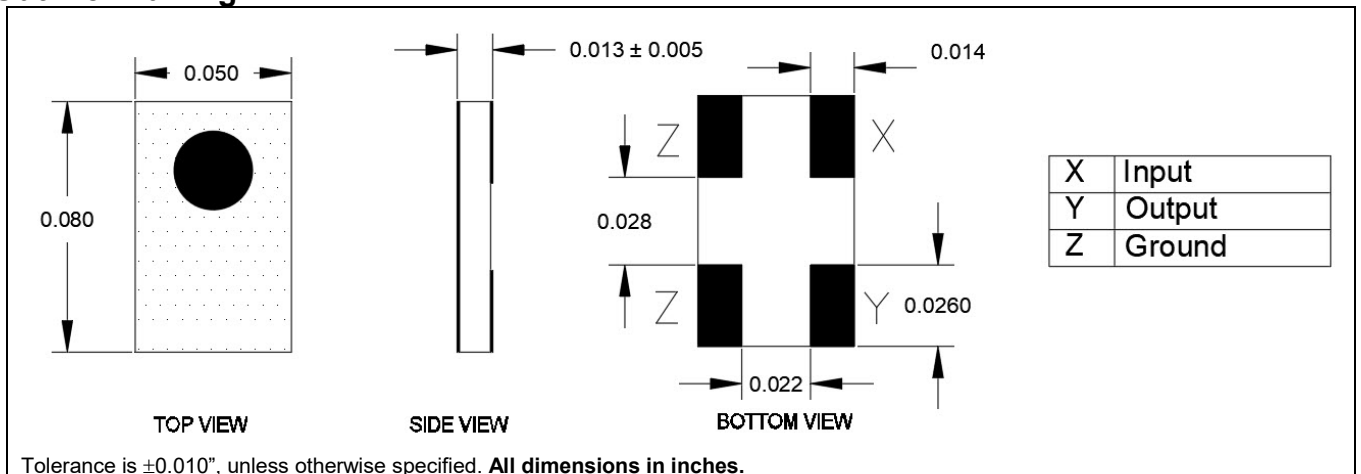
Resistive Element	Thick film
Substrate	Al ₂ O ₃ Ceramic
Terminal Finish	Matte Tin over Nickel Barrier
Operating Temperature	-55 to +150°C (see de-rating chart)

Electrical Specifications:

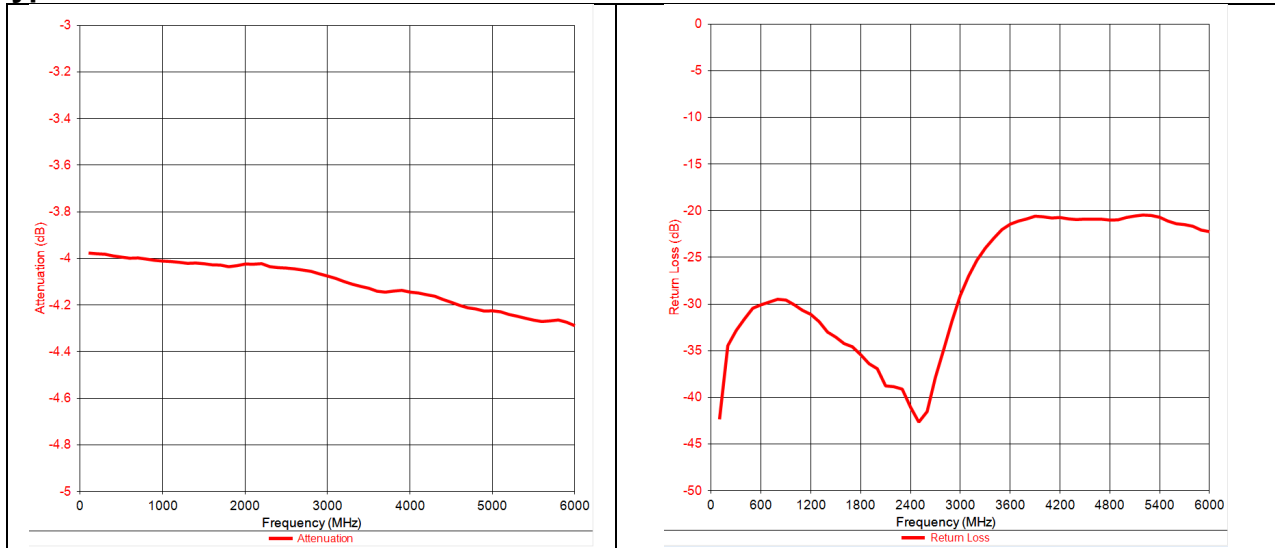
Attenuation Value:	4.0 ± 0.3 dB
Power:	2 Watts
Frequency Range:	DC – 6.0GHz
Input Return Loss:	20dB

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**

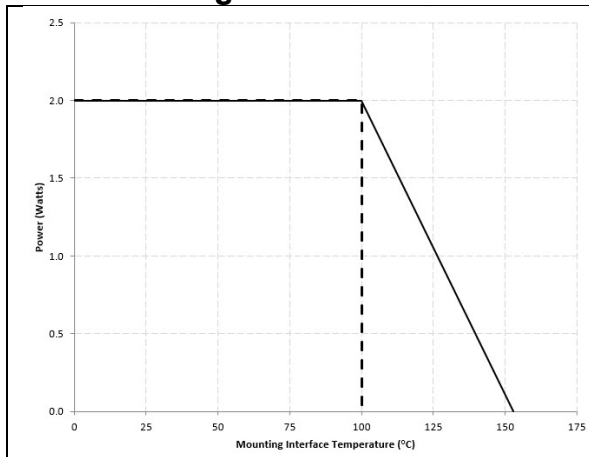
Outline Drawing:



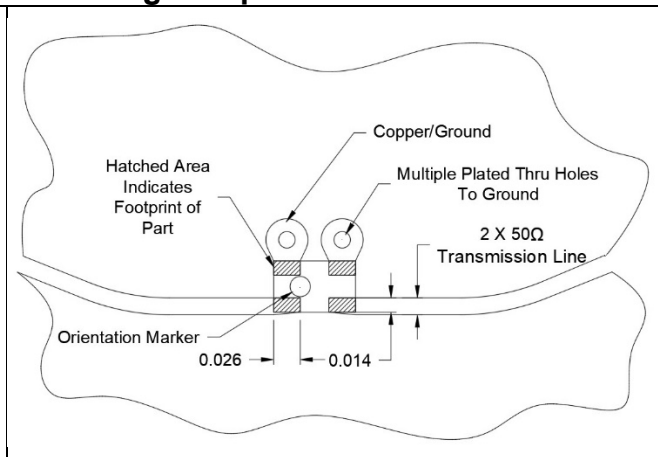
Typical Performance:



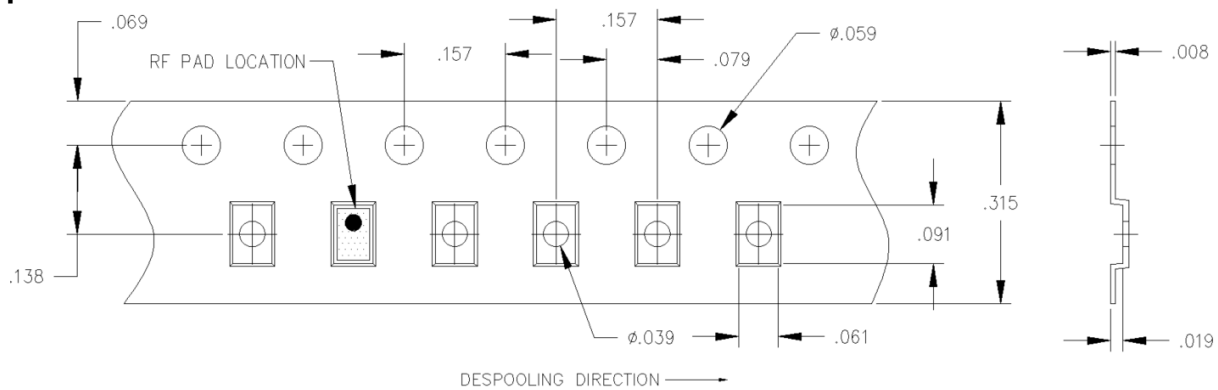
Power de-rating:



Mounting Footprint:



Tape & Reel:



TAPE DETAIL & RF PAD ORIENTATION

Contact us:
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